

C3D06060G

Silicon Carbide Schottky Diode

Z-REC[®] RECTIFIER

V_{RRM}	=	600 V
$I_F (T_c=135^\circ\text{C})$	=	9.5 A
Q_c	=	16 nC

Features

- 600-Volt Schottky Rectifier
- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- High-Frequency Operation
- Temperature-Independent Switching Behavior
- Extremely Fast Switching
- Positive Temperature Coefficient on V_F

Benefits

- Replace Bipolar with Unipolar Rectifiers
- Essentially No Switching Losses
- Higher Efficiency
- Reduction of Heat Sink Requirements
- Parallel Devices Without Thermal Runaway

Applications

- Switch Mode Power Supplies (SMPS)
- Boost diodes in PFC or DC/DC stages
- Free Wheeling Diodes in Inverter stages
- AC/DC converters

Package



TO-263-2



AEC-Q101 Qualified



Part Number	Package	Marking
C3D06060G	TO-263-2	C3D06060

Maximum Ratings ($T_c = 25^\circ\text{C}$ unless otherwise specified)

Symbol	Parameter	Value	Unit	Test Conditions	Note
V_{RRM}	Repetitive Peak Reverse Voltage	600	V		
V_{RSM}	Surge Peak Reverse Voltage	600	V		
V_{DC}	DC Blocking Voltage	600	V		Fig. 3
I_F	Continuous Forward Current	19 9 6	A	$T_c=25^\circ\text{C}$ $T_c=135^\circ\text{C}$ $T_c=154^\circ\text{C}$	
I_{FRM}	Repetitive Peak Forward Surge Current	30 20.5	A	$T_c=25^\circ\text{C}, t_p = 10 \text{ ms}$, Half Sine Wave $T_c=110^\circ\text{C}, t_p = 10 \text{ ms}$, Half Sine Wave	
I_{FSM}	Non-Repetitive Peak Forward Surge Current	63 49	A	$T_c=25^\circ\text{C}, t_p = 10 \text{ ms}$, Half Sine Wave $T_c=110^\circ\text{C}, t_p = 10 \text{ ms}$, Half Sine Wave	Fig. 8
I_{FSM}	Non-Repetitive Peak Forward Surge Current	540 460	A	$T_c=25^\circ\text{C}, t_p = 10 \mu\text{s}$, Pulse $T_c=110^\circ\text{C}, t_p = 10 \mu\text{s}$, Pulse	Fig. 8
P_{tot}	Power Dissipation	91 39	W	$T_c=25^\circ\text{C}$ $T_c=110^\circ\text{C}$	Fig. 4
dV/dt	Diode dV/dt ruggedness	200	V/ns	$V_R=0-600\text{V}$	
$\int i^2 dt$	i^2t value	19.8 12	A ² s	$T_c=25^\circ\text{C}, t_p=10 \text{ ms}$ $T_c=110^\circ\text{C}, t_p=10 \text{ ms}$	
T_J, T_{stg}	Operating Junction and Storage Temperature	-55 to +175	$^\circ\text{C}$		

Electrical Characteristics

Symbol	Parameter	Typ.	Max.	Unit	Test Conditions	Note
V_F	Forward Voltage	1.5 2.0	1.7 2.4	V	$I_F = 6\text{ A}$ $T_J = 25^\circ\text{C}$ $I_F = 6\text{ A}$ $T_J = 175^\circ\text{C}$	Fig. 1
I_R	Reverse Current	6.5 13	33 132	μA	$V_R = 600\text{ V}$ $T_J = 25^\circ\text{C}$ $V_R = 600\text{ V}$ $T_J = 175^\circ\text{C}$	Fig. 2
Q_C	Total Capacitive Charge	15		nC	$V_R = 400\text{ V}$, $I_F = 6\text{ A}$ $di/dt = 500\text{ A}/\mu\text{s}$ $T_J = 25^\circ\text{C}$	Fig. 5
C	Total Capacitance	295 28.5 25.5		pF	$V_R = 0\text{ V}$, $T_J = 25^\circ\text{C}$, $f = 1\text{ MHz}$ $V_R = 200\text{ V}$, $T_J = 25^\circ\text{C}$, $f = 1\text{ MHz}$ $V_R = 400\text{ V}$, $T_J = 25^\circ\text{C}$, $f = 1\text{ MHz}$	Fig. 6
E_C	Capacitance Stored Energy	2.3		μJ	$V_R = 400\text{ V}$	Fig. 7

Note: This is a majority carrier diode, so there is no reverse recovery charge.

Thermal Characteristics

Symbol	Parameter	Typ.	Unit
$R_{\theta JC}$	Thermal Resistance from Junction to Case	1.65	$^\circ\text{C}/\text{W}$

Typical Performance

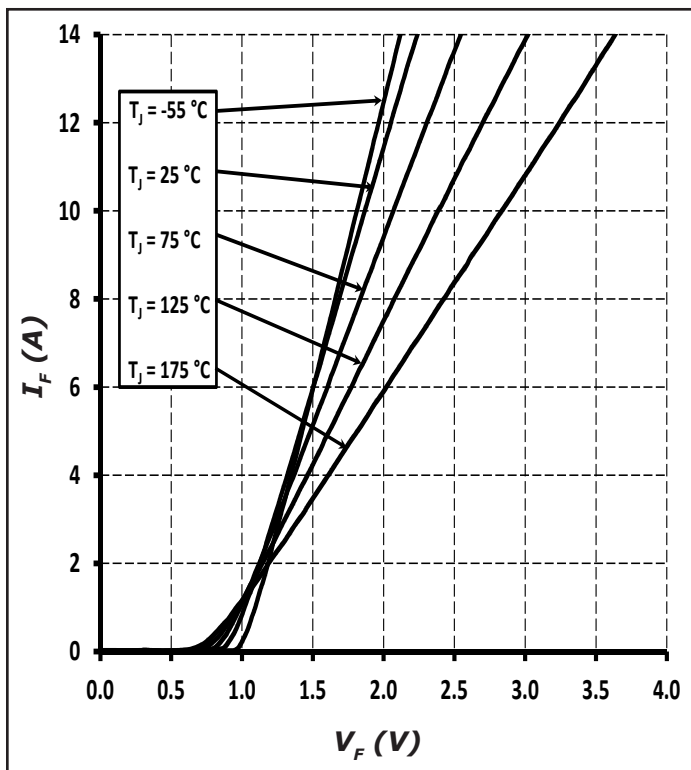


Figure 1. Forward Characteristics

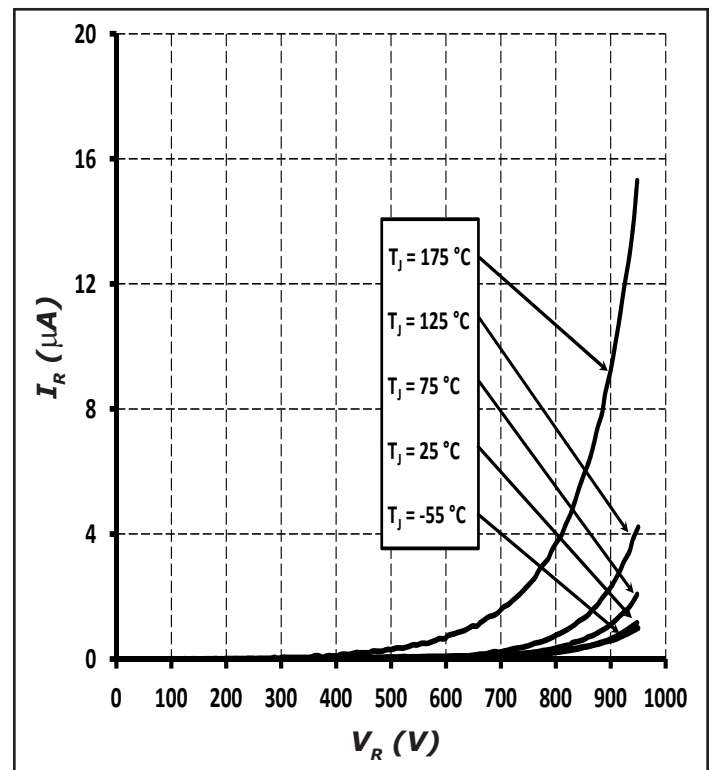


Figure 2. Reverse Characteristics

Typical Performance

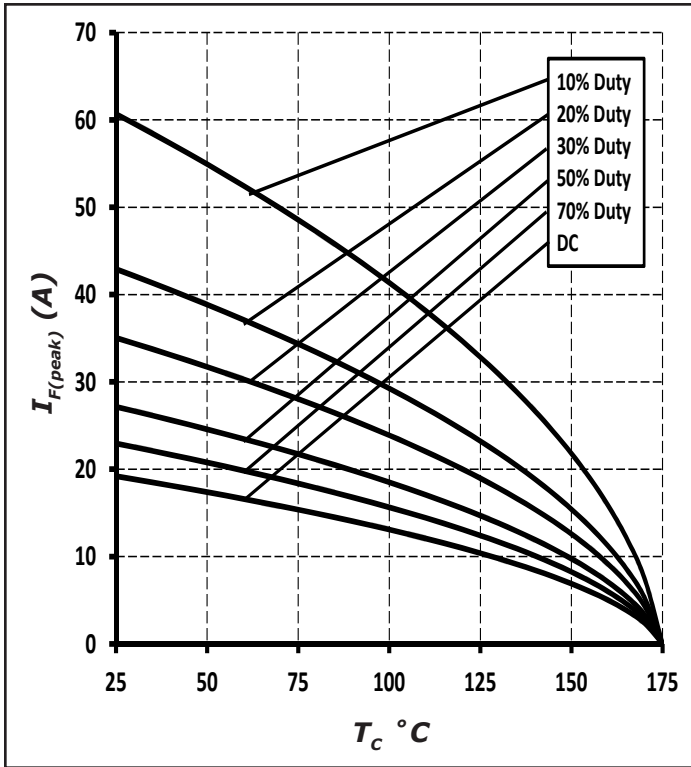


Figure 3. Current Derating

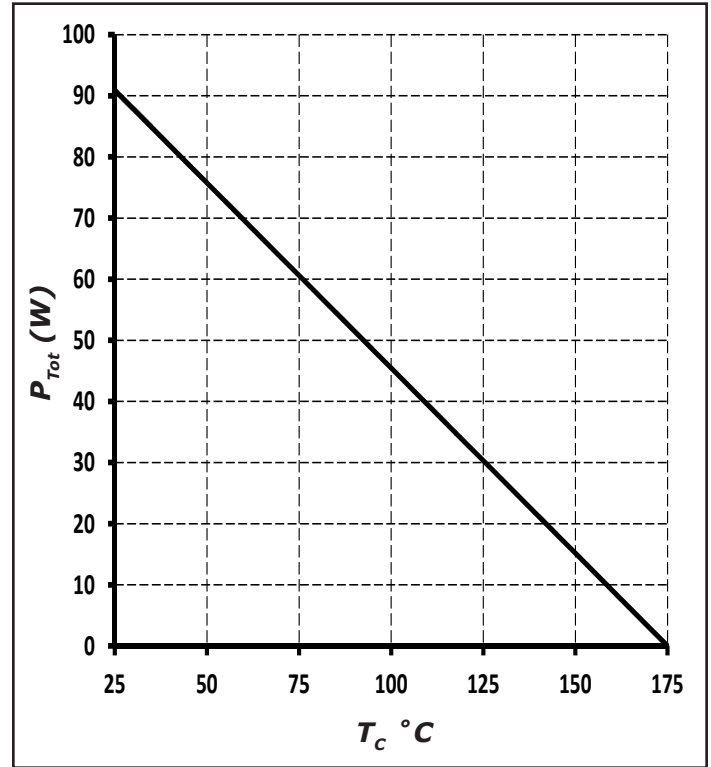


Figure 4. Power Derating

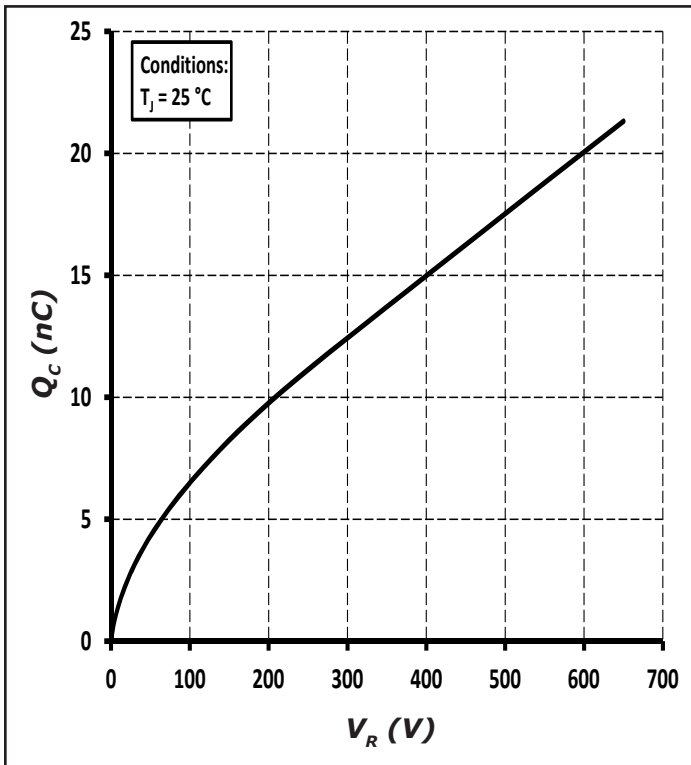


Figure 5. Total Capacitance Charge vs. Reverse Voltage

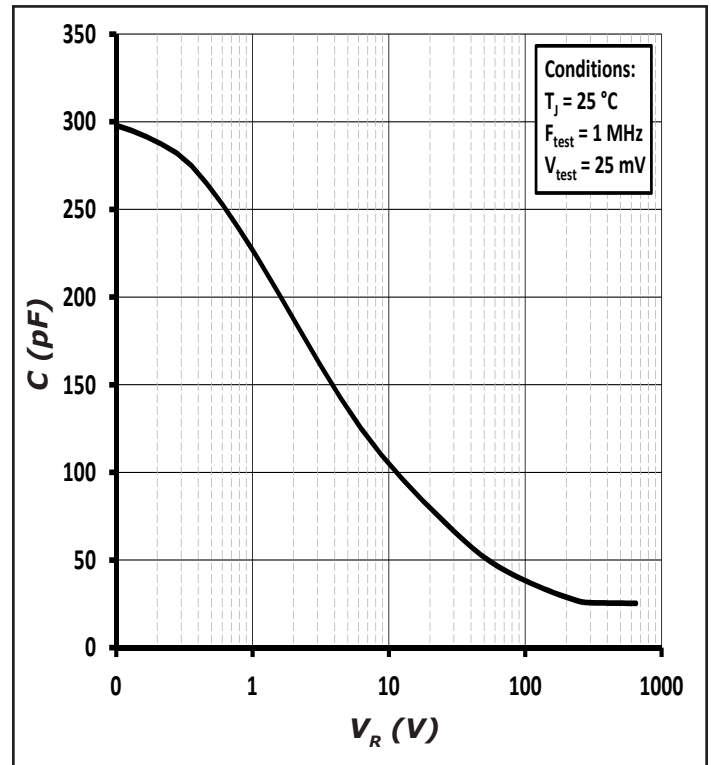


Figure 6. Capacitance vs. Reverse Voltage

Typical Performance

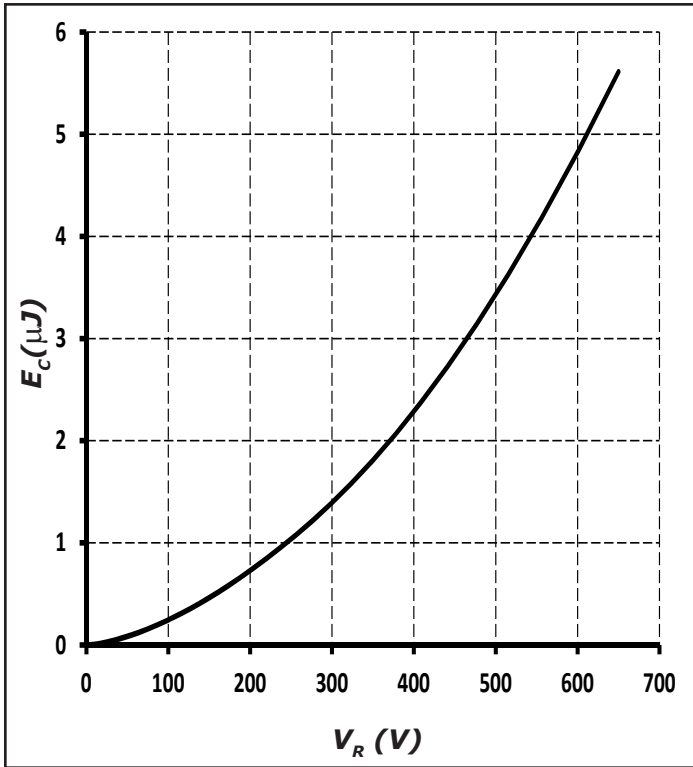


Figure 7. Capacitance Stored Energy

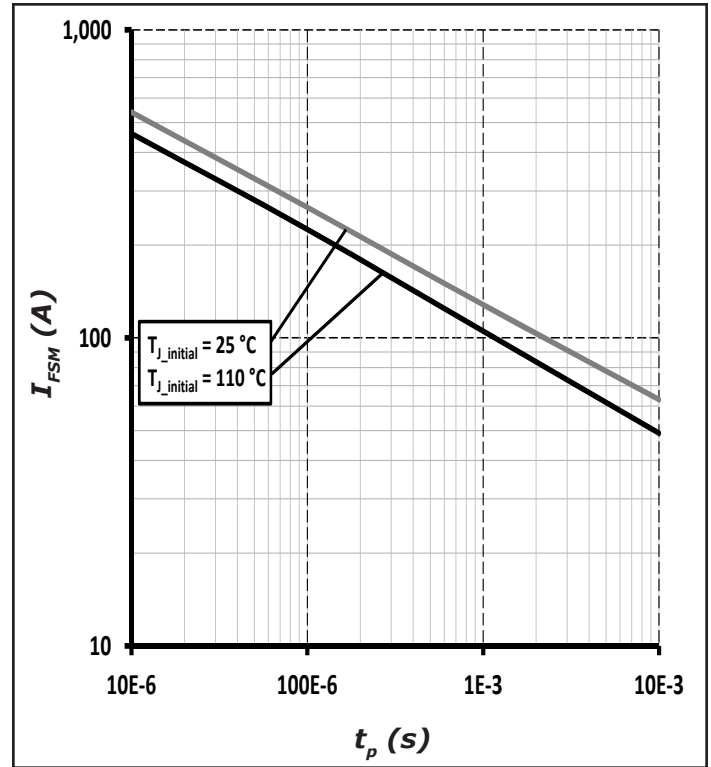


Figure 8. Non-repetitive peak forward surge current versus pulse duration (sinusoidal waveform)

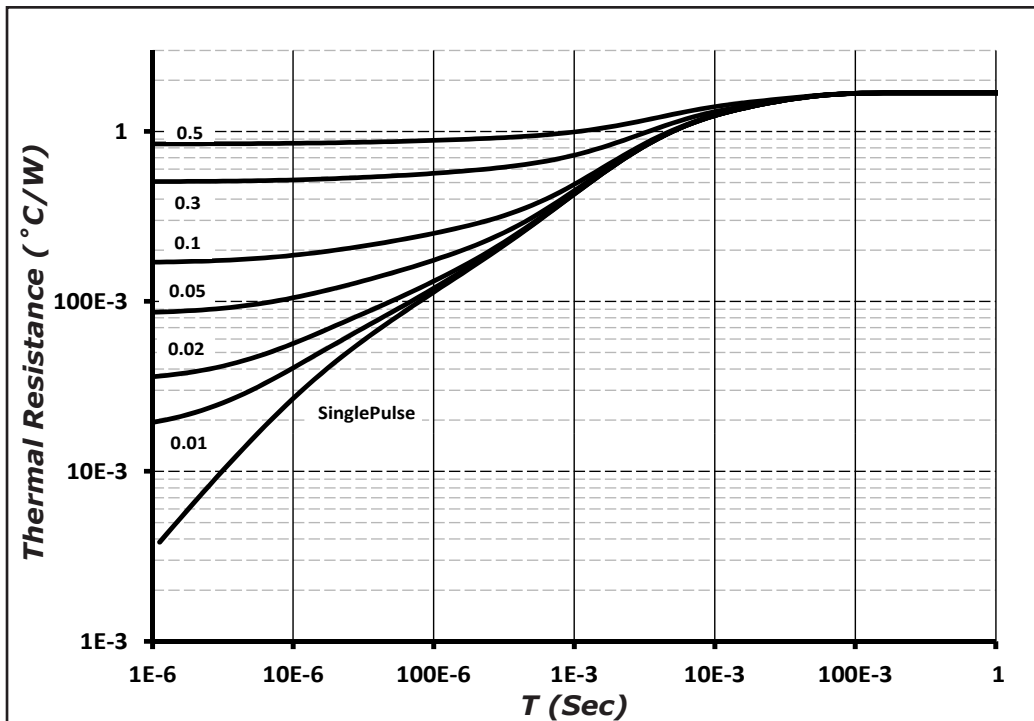
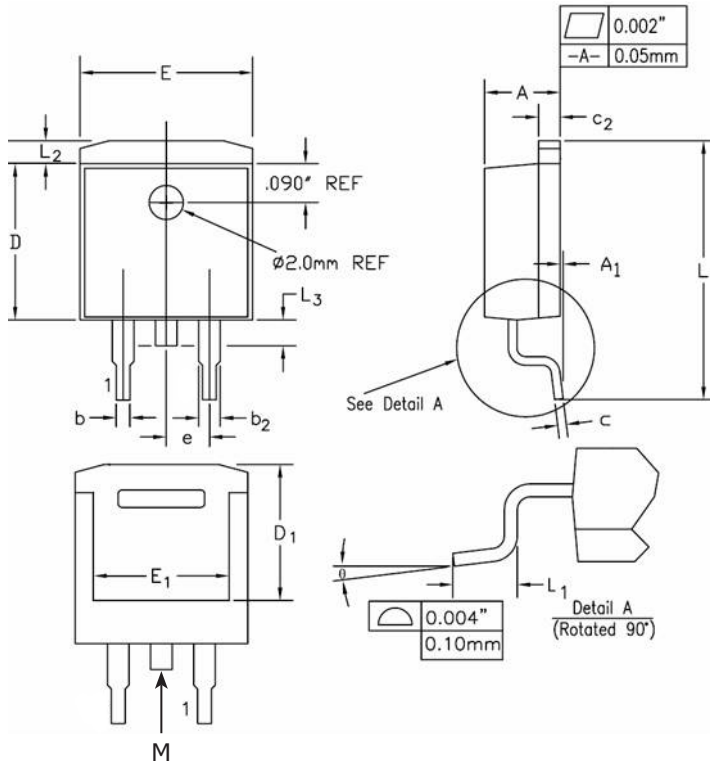


Figure 9. Transient Thermal Impedance

Package Dimensions

Package TO-263-2

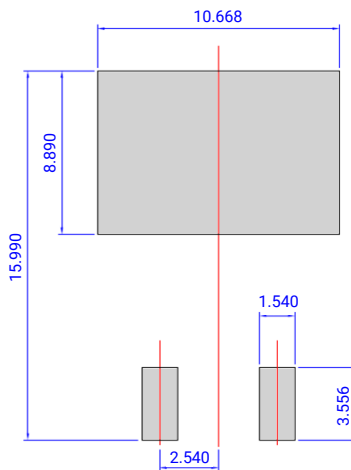


POS	Inches		Millimeters	
	Min	Max	Min	Max
A	0.17	0.18	4.32	4.57
A1	-	0.01	-	0.25
b	0.028	0.037	0.71	0.94
b2	0.045	0.055	1.15	1.4
c	0.014	0.025	0.356	0.635
c2	0.048	0.055	1.22	1.4
D	0.35	0.37	8.89	9.4
D1	0.255	0.324	6.48	8.23
E	0.395	0.405	10.04	10.28
E1	0.31	0.318	7.88	8.08
e	0.1	BSC.	2.54	BSC.
L	0.58	0.62	14.73	15.75
L1	0.09	0.11	2.29	2.79
L2	0.045	0.055	1.15	1.39
L3	0.05	0.07	1.27	1.77
θ	0°	8°	0°	8°

Note: Tab "M" may not be present



Recommended Solder Pad Layout



Part Number	Package	Marking
C3D06060G	TO-263-2	C3D06060

Note: Recommended soldering profiles can be found in the applications note here: http://www.wolfspeed.com/power_app_notes/soldering

